NSN 5961-01-259-2016

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-259-2016 **Inclosure Material:** Glass **Overall Length:** 0.250 inches **Terminal Length:** 0.120 inches **Overall Diameter:** 0.138 inches **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 45.0 reverse breakdown voltage, dc all semiconductor device diode **Voltage Tolerance In Percent:** -20.0/+20.0 all semiconductor device diode **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No